

Frequency Synthesizer for TV and VCR Tuner with Universal Bus

Description

The U6224B is a single chip frequency synthesizer with bi-directional I²C-bus control and an unidirectional 3-wire bus control, developed for TV-tuner applications. This IC contains an integrated preamplifier, a high frequency prescaler, a reference divider with program-

mable divider ratios, a crystal oscillator, a phase/frequency detector together with a charge pump and a tuning amplifier. It perform also a EASY LINK interface to MOSMIC and Mixer IC.

Features

- 1.3 GHz divide-by-8 prescaler integrated (can be bridged)
- Easy-link interface to MOSMIC and MIXER-IC
- Universal bus: I²C-bus **or** 3-wire-bus
- 3-wire-bus mode:
 - 3 unidirectional output ports (open collector)
 - lock output (open collector)
- I²C-bus mode:
 - 3 bidirectional ports (open collector)
 - 5 level ADC or unidirectional port (open collector)
 - 3 addresses selectable at Pin 10 and 1 address fixed for multituner application
- Low-power consumption (typ. 5 V / 35 mA)
- Electrostatic protection according to MIL-STD 883
- SO16 small package

Block Diagram

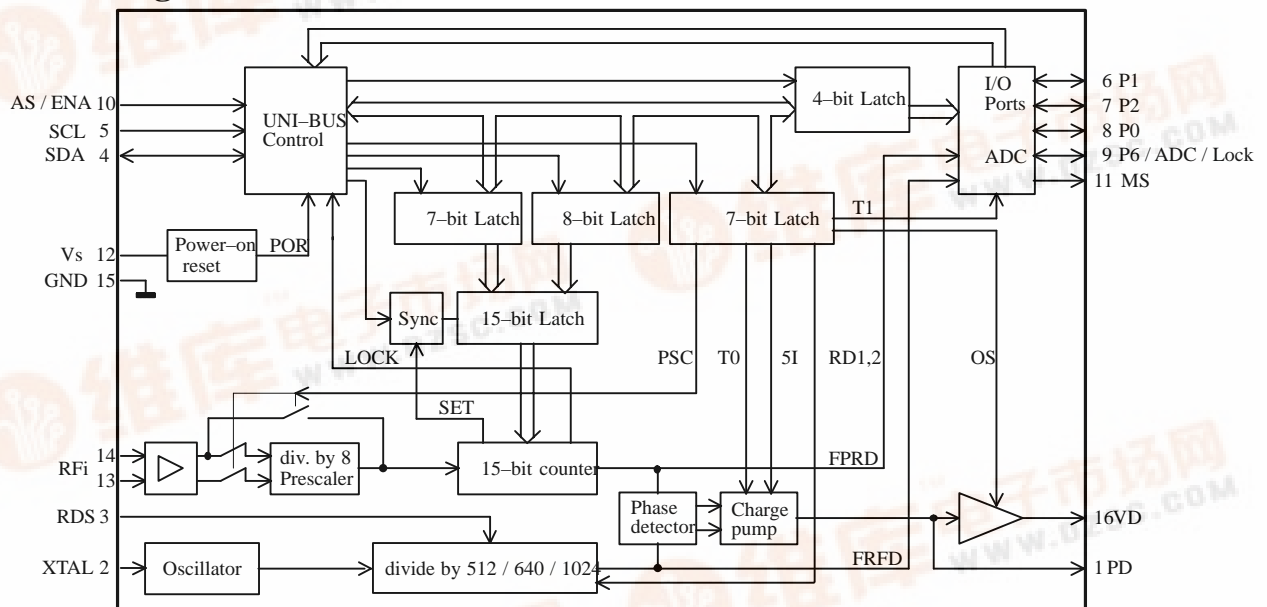


Figure 1. Block diagram

Ordering Information

U6224B-MFP	SO16	
U6224B-MFPG3	SO16	Taped and reeled

Pin Description

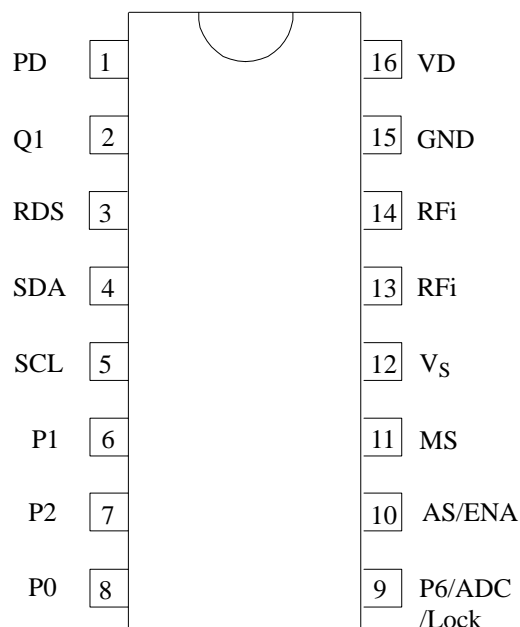


Figure 2. Pinning

Pin	Symbol	Function
1	PD	Charge pump output
2	Q1	XTAL
3	RDS	Reference divider select input
4	SDA	Data input / output
5	SCL	Clock input
6	P1	Input / output port
7	P2	Input / output port
8	P0	Input / output port
9	P6/ADC/ Lock	Port output / ADC-input / Lock output
10	AS/ENA	Address select / Enable input
11	MS	Mixer switch output
12	Vs	Supply voltage
13	RFi	RF input
14	RFi	RF input
15	GND	Ground
16	VD	Active filter output

Description

The U6224B is a single chip-PLL designed for TV and VCR receiver systems. It consists of a bridgeable divide-by-8 prescaler with an integrated preamplifier, a 15-bit programmable divider, a crystal oscillator and a reference divider with three selectable divider ratios ($\div 512/\div 640/\div 1024$), and phase/ frequency detector with a charge-pump which is driving the tuning amplifier. Only one external transistor is required for varactor line driving. The device can be controlled via the I²C-bus or the 3-wire-bus format. It detects automatically which bus format is received, therefore, there is no need for a bus selection pin. In I²C-bus mode, the device has one fixed I²C-bus address and three programmable addresses. Programming is carried out by applying a specific input voltage to the address select input, enabling the use of up to three synthesizers in a system. This pin serves in 3-wire-bus mode as the enable signal input. Four open-collector outputs are available for switching functions. In 3-wire-bus mode, there are three open-collector outputs. One of them serves as Lock signal output. The logic of the output ports P0-2 is inverted in order to drive gate 1 of MOSMIC prestages directly without change in software. This feature removes the formerly external pnp switching transistors. All open collector outputs are capable of sinking at least 10 mA. The MS output is provided to control directly a mixer-oscillator IC in combination with the output port P0-2 state.

In I²C-bus mode, an Analog-to-Digital Converter is available for digital AFC control applications and the ports P0-2 can be used as inputs.

Functional Description

The U6224B is programmed via the 2-wire I²C-bus or the 3-wire-bus depending on the received data format. The three bus inputs Pins 4, 5 and 10 are used as SDA, SCL and address select inputs in I²C-bus mode or as data, clock and enable inputs in 3-wire-bus mode. The data includes the scaling factor SF and switching output information. In I²C-bus mode, are some additional functions are available (ADC, bidirectional ports, etc.).

Oscillator frequency calculation:

$$f_{VCO} = PSF \times SPF \times f_{refosc}/SRF$$

f_{VCO} : Locked frequency of voltage controlled oscillator

PSF: Scaling factor of prescaler ($\div 1$ or $\div 8$ in I²C-/ $\div 8$ in 3-wire-bus mode)

SPF: Scaling factor of programmable divider (15 bit in I²C-/14 bit in 3-wire-bus mode)

SRF: Scaling factor of reference divider ($\div 512/\div 640/\div 1024$)

f_{refosc} : Reference oscillator frequency: 3.2/4 MHz crystal or external reference frequency

The input amplifier together and the divide-by-8 prescaler enable an excellent sensitivity (see figures 7 and 8). The input impedance is shown in the figure 16. When a new divider ratio according to the requested f_{VCO} is entered, the phase detector and charge pump together with the tuning amplifier adjust the control voltage of the VCO until the output signals of the programmable divider and the reference divider are in frequency and phase locked. The reference frequency may be provided by an external source capacitively coupled into Pin 2, or by using an on-board crystal with an 18-pF capacitor in series. The crystal operates in series resonance mode. The reference divider division ratio is selectable to $\div 512/\div 640/\div 1024$. Using a 4-MHz crystal and the nominal division ratio of 512 of the reference divider, the

comparison frequency is 7.8125 kHz, resulting in 62.5-kHz steps for the VCO. Using a 3.2-MHz crystal results in 6.25 kHz comparison frequency and 50-kHz VCO step size. In I²C-bus mode, the division ratio may be set via two bits, in 3-wire-bus mode via a voltage at Pin 3. In addition, port outputs for band switching and other purposes are available.

Application

A typical application is shown on page 14. All input/output interface circuits are shown on pages 12 and 13. Some special features related to test- and alignment procedures for tuner production are explained in the following bus-mode description.

Absolute Maximum Ratings

All voltages are referred to GND (Pin 15).

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	Pin 12	V _s	-0.3		6	V
RF input voltage	Pin 13, 14	RFi	-0.3		V _s +0.3	V
Xtal input voltage	Pin 2	Q1	-0.3		V _s +0.3	V
Charge pump output voltage	Pin 1	PD	-0.3		V _s +0.3	V
Active filter output voltage	Pin 16	VD	-0.3		V _s +0.3	V
Bus input/output voltage	Pin 4, 5	VSDA, VSCL	-0.3		6	V
SDA output current	open collector Pin 4	ISDA	-1		5	mA
Address select/ENA input	Pin 10	VAS/ENA	-0.3		V _s +0.3	V
Port output current	open collector Pin 6-9	P0-2, P6	-1		15	mA
Total port output current	open collector Pin 6-9	P0-2, P6	-1		50	mA
Port input/output voltage	in off-state Pin 6-9	P0-2, P6	-0.3		15	V
Port output voltage	in on-state Pin 6-9	P0-2, P6	-0.3		6	V
Junction temperature		T _{jmax}	-40		125	°C
Storage temperature		T _{stg}	-40		125	°C

Operating Range

All voltages are referred to GND (Pin 15).

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	Pin 12	V _s	4.5	5	5.5	V
Ambient temperature		T _{amb}	0		70	°C
Input frequency	PSC = 1 Pin 13, 14	RFi	80		1300	MHz
Input frequency	PSC = 0 Pin 13, 14	RFi	1		220	MHz
Programmable divider	I ² C-bus mode	SF	256		32767	
Programmable divider	3-wire-bus mode	SF	256		16383	
Xtal oscillator	Pin 2	f _{Xtal}	3	4	4.48	MHz

Thermal Resistance

All voltages are referred to GND (Pin 15).

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Thermal resistance	SO16 small	RthJA			110	K/W

Electrical Characteristics

Test conditions (unless otherwise specified): $V_s = 5\text{ V}$, $T_{amb} = 25\text{ °C}$

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply current (prescaler on)	P0-2 = 1; P6 = 0; PSC = 1 Pin 12	I _s		35		mA
Supply current (prescaler off)	P0-2 = 1; P6 = 0; PSC = 0 Pin 12	I _s		21		mA
Input sensitivity						
f _{RFI} = 80-1000 MHz	PSC = 1 Pin 13	V _i ¹⁾	10		315	mVrms
f _{RFI} = 1300 MHz	PSC = 1 Pin 13	V _i ¹⁾	40		315	mVrms
f _{RFI} = 10-220 MHz	PSC = 0 Pin 13	V _i ¹⁾	10		315	mVrms
Crystal oscillator						
Recommended crystal series resistance			10		200	Ω
Crystal oscillator drive level	Pin 2			50		mVrms
Crystal oscillator source impedance	Nominal spread ±15 % Pin 2			-650		Ω
External reference input frequency	AC-coupled sinewave Pin 2		3		4.5	MHz
External reference input amplitude	AC-coupled sinewave Pin 2		70		200	mVrms
Port outputs/lock output (open collector), Lock condition: low, P0-2, P6, Lock						
Leakage current	V _H = 13.5 V Pins 6-9	I _L			10	μA
Saturation voltage	I _L = 10 mA Pins 6-9	V _{SL} ²⁾			0.5	V
Port inputs (P0-2)						
Input voltage high	Pins 6-8	V _i 'H'	2.7			V
Input voltage low	Pins 6-8	V _i 'L'			0.8	V
Input current high	V _i 'H' = 13.5 V Pins 6-8	I _i 'H'			10	μA
Input current low	V _i 'L' = 0 V Pins 6-8	I _i 'L'	-10			μA
ADC input (ADC), see page 7 for ADC-levels						
Input current high	V _i 'H' = 13.5 V Pin 9	I _i 'H'			10	μA
Input current low	V _i 'L' = 0 V Pin 9	I _i 'L'	-10			μA
Charge pump output (PD)						
Charge pump current 'H'	5I = 1, VPD = 1.7 V Pin 1	IPDH		±180		μA
Charge pump current 'L'	5I = 0, VPD = 1.7 V Pin 1	IPDL		±50		μA
Charge pump leakage current	TO = 1, VPD = 1.7 V Pin 1	IPDTRI		±5		nA
Charge pump amplifier gain	Pins 1, 16			6400		

Notes: 1) RMS-voltage calculated from the available power measured at 50 Ω.

2) Tested with one port active. The collector voltage of an active port may not exceed 6 V.

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Bus inputs (SDA, SCL)						
Input voltage high	Pin 4, 5	Vi‘H’	3		5.5	V
Input voltage low	Pin 4, 5	Vi‘L’			1.5	V
Input current high	Vi‘H’ = Vs Pin 4, 5	Ii‘H’			10	μA
Input current low	Vi‘L’ = 0 V Pin 4, 5	Ii‘L’	–20			μA
Output voltage SDA (open collector)	ISDA‘L’ = 3 mA Pin 4	VSDA ‘L’			0.4	V
Address selection/Enable input (AS/ENA)						
Input current high	Vi‘H’ = Vs Pin 10	Ii‘H’			10	μA
Input current low	Vi‘L’ = 0 V Pin 10	Ii‘L’	–10			μA
Mixer switch output (MS)						
Output voltage band A	I MS = –20 μA Pin 11	V MSA	0	0.25	1	V
Output voltage band B	I MS = –20 μA Pin 11	V MSB	1.6	0.4*Vs	2.4	V
Output voltage band C	I MS = –20 μA Pin 11	V MSC	Vs–1	Vs–.75	Vs	V

I²C-Bus Description

Functional Description

When the U6224B is controlled via the 2-wire I²C-bus format, then data and clock signals are fed into the SDA and SCL lines respectively. Depending on the LSB of the address byte, the device can either accept new data (write mode: LSB = 0) or send data (read mode: LSB = 1). The device has one fixed and three programmable I²C-bus addresses. The tables ‘I²C-BUS WRITE DATA FORMAT’ and ‘I²C-BUS READ DATA FORMAT’ describe the format of the data and show how to select the device address by applying a voltage at Pin 10.

Write Mode (Address byte LSB = 0)

When write mode is activated and the correct address is received, the SDA line is pulled low by the device during the acknowledge period, and then also during the acknowledge periods, when additional data bytes are programmed. After the address transmission (first byte), data bytes can be sent to the device. There are four data bytes requested to fully program the device. Once the correct address is received and acknowledged, the first bit of the following byte determines whether that byte is interpreted as byte 2 or 4; a logic 0 for divider information and a logic 1 for control and port output information. When byte 2 was received the device always expects byte 3 next. Likewise when byte 4 was received, byte 5 is expected. Additional data bytes can be entered without the need to re-address the device to the device until an I²C-bus stop condition is recognized. This allows a smooth frequency sweep for fine tuning AFC purposes. The table ‘I²C-BUS PULSE DIAGRAM’ shows some possible data transfer examples.

The programmable divider bytes PDB1 and PDB2 are controlling the division ratio of the 15 bit programmable

divider. They are loaded in a 15 bit latch after the 8th clock pulse of the second divider byte PDB2, the control and the port register latches are loaded after the 8th clock pulse of the control byte CB1 resp. port byte CB2.

The control byte CB1 allows to control the following special functions:

- 5I-bit switches between low and high charge pump current
- T1-bit enables divider test mode when it is set to logic 1
- T0-bit allows to disable the charge pump when it is set to logic 1
- PSC-bit switches prescaler off when it is set to logic 0
- RD1 and RD2-bit allow to select the reference divider ratio
- OS-bit disables the charge pump drive amplifier output when it is set to logic 1.

The charge pump current can be controlled in I²C-bus mode only.

The OS-bit function disables the complete PLL function. This allows the tuner alignment by supplying the tuning voltage directly through the 30 V supply voltage of the tuner.

The control byte CB2 programs the port outputs P0-2 and P6; for the MOSMIC ports P0-2 a logic 1 for high impedance output (off) or a logic 0 for low impedance output and for the standard port P6 a logic 0 for high impedance output (off) or a logic 1 for low impedance output (on). At power-on the MOSMIC ports P0-2 are set to low impedance state and the standard port P6 to high impedance state.

Description	I ² C Bus Write Data Format								
	MSB					LSB			
Address byte	1	1	0	0	0	AS1	AS2	0	A
Progr. divider byte 1	0	n14	n13	n12	n11	n10	n9	n8	A
Progr. divider byte 2	n7	n6	n5	n4	n3	n2	n1	n0	A
Control byte 1	1	5I	T1	T0	PSC	RD2	RD1	OS	A
Control byte 2	X	P6	X	X	X	P2	P1	P0	A

A = Acknowledged; X = not used; unused bits of control byte 2 should be 0 for lowest power consumption

n0 ... n14:	Scaling factor (SF)	$SF = 16384 \times n14 + 8192 \times n13 + \dots + 2 \times n1 + n0$	
PSC:	Prescaler on/off	PSC = 1: prescaler on	PSC = 0: prescaler off
T0, T1:	Test mode selection	T1 = 1: divider test mode on fPRD at Pin 6, fRFD at Pin 7 T1 = 0: divide test mode off T0 = 1: charge pump disable T0 = 0: charge pump enable	
P0-2:	Port outputs (for MOSMIC'S)	P0, 1, 2 = 0: open collector active for MOSMIC gate 1 logic	
P6:	Port outputs	P6 = 1: open collector active	
5I:	Charge pump current switch	5I = 1: high current	5I = 0: low current
OS:	Output switch	OS = 1: varicap drive disable	OS = 0: varicap drive enable

RD1, RD2: Reference Divider Selection	RD2	RD1	Reference Divider Ratio
	X	0	640
	0	1	1024
	1	1	512

AS1, AS2: Address Selection Pin 10	AS1	AS2	Address	Dec. Value	Voltage at Pin 10
	0	1	1	194	always valid
	0	0	2	192	0 to 10 % Vs
	1	0	3	196	40 to 60 % Vs
	1	1	4	198	90 % Vs to 13.5 V

Mixer-Switch Output Levels	P2	P1	P0	MS Output Voltage	Band Selection
	0	1	0	< 0.25 V	Band A
	1	0	0	$0.4 \times V_s$	Band B
	0	0	1	$V_s - 0.75 \text{ V}$	Band C

Read Mode (Address byte LSB = 1)

After the address transmission (first byte), the status byte can be read from the device on the SDA line (MSB first). Data is valid on the SDA line during logic high of the SCL signal. The controller accepting the data has to pull the SDA line to low-level during all status byte acknowledge periods to read another status byte. If the controller fails to pull the SDA line to low-level during this period, the device will release the SDA line to allow the controller to generate a STOP condition.

The POR-bit (power-on-reset) is set to a logic 1 when the supply voltage V_s of the device has dropped below 3 V (at 25 °C) and also when the device is initially turned on. The POR-bit is reset to a logic 0 when the read sequence is terminated by a STOP condition. When POR-bit is set high (at low V_s) it is indicated that all programmed informa-

tion is lost and the port outputs are all set to high impedance state.

The FL-bit indicates whether the loop is in phase lock condition (logic 1) or not (logic 0).

If the ADC or the ports are to be used as inputs, the corresponding outputs must be programmed to a high impedance state (logic 1).

The bits I2, I1 and I0 show the status of the I/O ports P0, P1 and P2 respectively. A logic 0 indicates a LOW level and a logic 1 a HIGH level (TTL levels).

The bits A2, A1 and A0 represent the digital information of the 5-level ADC. This converter can be used to feed AFC information to the controller from the IF section of the receiver, as shown in the typical application circuit on page 14.

Description	I ² C Bus Read Data Format								
	MSB					LSB			
Address byte	1	1	0	0	0	AS1	AS2	1	A
Status byte	POR	FL	I2	I1	I0	A2	A1	A0	–

POR: Power-on-reset flag: POR = 1 on power on

FL: in-lock flag: FL = 1, when loop is phase locked

I2, I1, I0: digital information of I/O-ports P0, P1 and P2 respectively

A2, A1, A0: digital data of the 5-level ADC. see next table

A/D Converter Levels	A2	A1	A0	Input Voltage to ADC Pin 9
	1	0	0	60 % V_s to 13.5 V
	0	1	1	45 % to 60 % V_s
	0	1	0	30 % to 45 % V_s
	0	0	1	15 % to 30 % V_s
	0	0	0	0 V to 15 % V_s

I²C-Bus Pulse Diagram

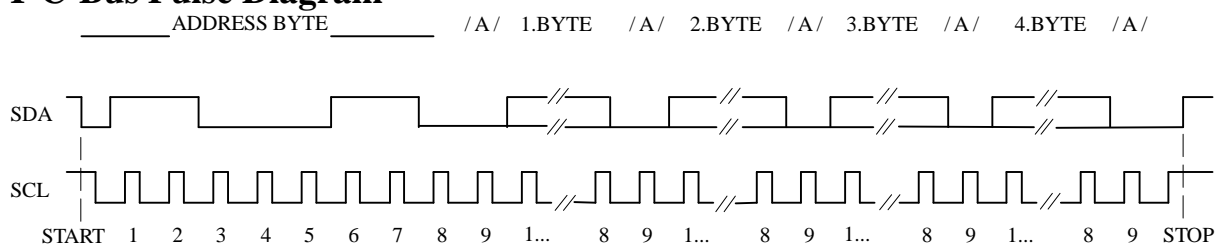


Figure 3. Pulse diagram

Data transfer examples

START – ADR – PDB1 – PDB2 – CB1 – CB2 – STOP
 START – ADR – CB1 – CB2 – PDB1 – PDB2 – STOP
 START – ADR – PDB1 – PDB2 – CB1 – STOP
 START – ADR – PDB1 – PDB2 – STOP
 START – ADR – CB1 – CB2 – STOP
 START – ADR – CB1 – STOP

Description

START = Start condition
 ADR = Address byte
 PDB1 = Progr. divider byte 1
 PDB2 = Progr. divider byte 2
 CB1 = Control byte 1
 CB2 = Control byte 2
 STOP = Stop condition

I²C-Bus Timing

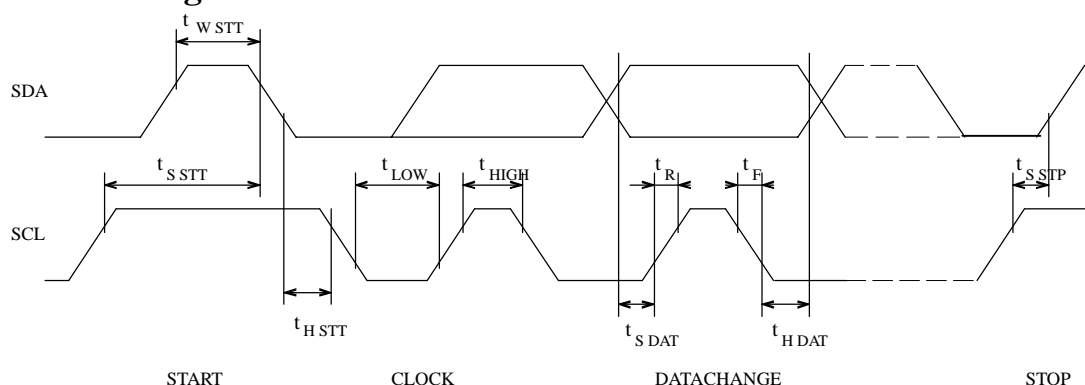


Figure 4. Bus timing

Parameters	Test Conditions / Pins	Symbol	Min.	Max.	Unit
Rise time SDA, SCL		tR		15	μs
Fall time SDA, SCL		tF		15	μs
Clock frequency SCL		fSCL	0	100	kHz
Clock 'H' pulse		tHIGH	4		μs
Clock 'L' pulse		tLOW	4		μs
Hold time start		tH STT	4		μs
Waiting time start		tW STT	4		μs
Setup time start		tS STT	4		μs
Setup time stop		tS STP	4		μs
Setup time data		tS DAT	0.3		μs
Hold time data		tH DAT	0		μs

3-Wire-Bus Description

When the U6224B is controlled via 3-wire-bus format, then data, clock and enable signals are fed into the SDA, SCL and AS/ENA lines respectively. Figure 5 shows the data format. The data consists of a single word which contains the programmable divider (14 bit) and port information. Bit no. 15 of the programmable divider is always zero when 3-wire-bus mode is active. Only during the enable high period, the data is clocked into the internal data shift register on the negative clock transition. During enable low periods, the clock input is disabled. New data words are only accepted by the internal data latches from the shift register on a negative transition of the enable signal when exactly eighteen clock pulses were sent during the high period of the enable. The data sequence and the timing is described in the following diagrams.

In 3-wire-bus mode, Pin 9 becomes automatically the Lock signal output. An improved lock detect circuit generates a flag when the loop has attained lock. 'In lock' is indicated by a low impedance at on state of the open collector output.

In 3-wire-bus mode, the following conditions are set internally:

- 5I = 1: always high, charge pump current active
- T1 = 0: divider test mode off
- T0 = 0: charge pump enable
- RD1, 2 = X: reference divider ratio is selected through RDS input
- PSC = 1: prescaler on
- OS = 0: varicap enable

In 3-wire-bus mode, the division ratio of the reference divider may be selected by applying an appropriate voltage at the RDS input Pin 3.

The complete PLL function can be disabled by programming a normally not used division ratio of zero. This allows the tuner alignment by supplying the tuning voltage directly through the 30-V supply voltage of the tuner.

RDS: Reference Divider Selection Pin 3	Reference Divider Ratio	Voltage at Pin 3
	1024	0% to 10% Vs
	512	open or 40% to 60% Vs
	640	90% to 100% Vs

3-Wire-Bus Pulse Diagram

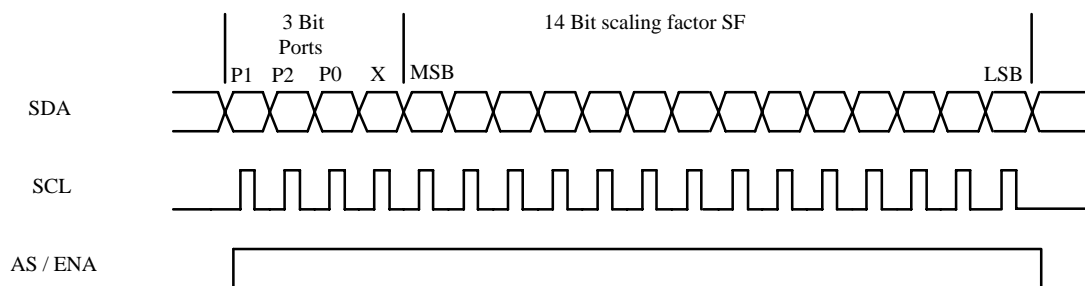


Figure 5. Pulse diagram

3-Wire-Bus Timing

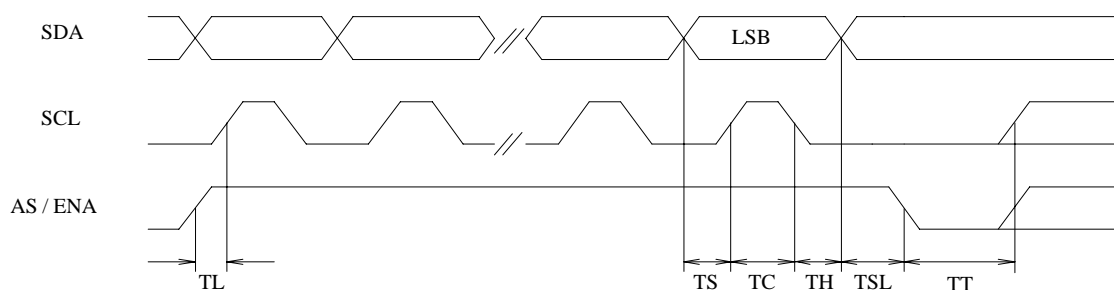


Figure 6. Bus timing

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Setup time		TS	2			μs
Enable hold time		TSL	2			μs
Clock width		TC	2			μs
Enable setup time		TL	10			μs
Enable between two transmissions		TT	10			μs
Data hold time		TH	2			μs

Typical Prescaler Input Sensitivity (Prescaler on: PSC = 1)

V_i (mV RMS on 50 Ohm)

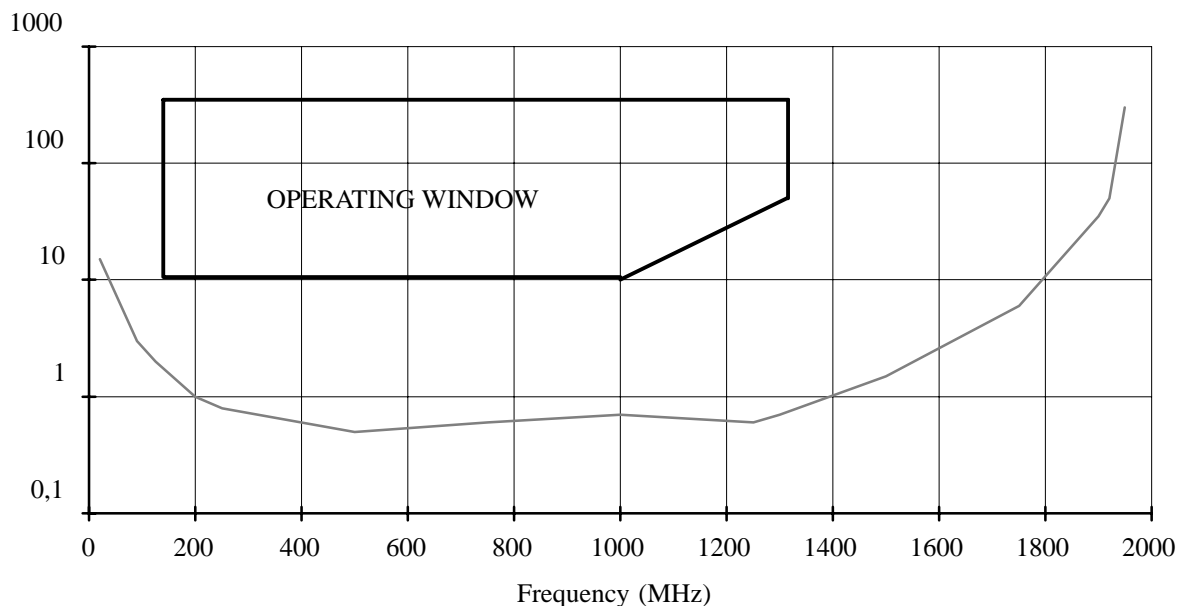


Figure 7.

Typical Prescaler Input Sensitivity (Prescaler off: PSC = 0)

V_i (mV RMS on 50 Ohm)

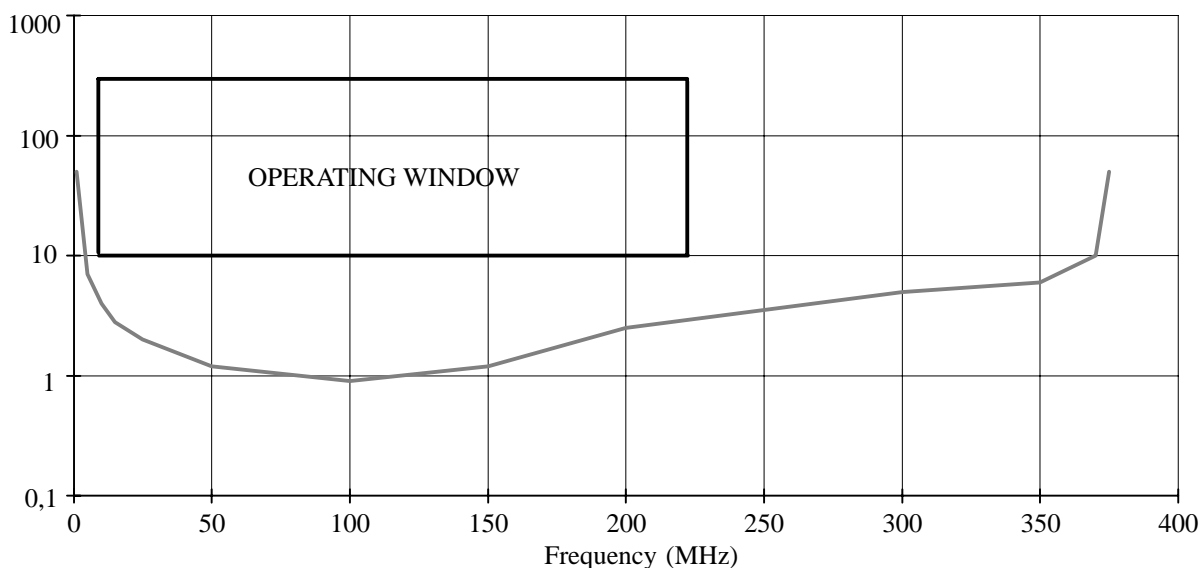


Figure 8.

Input/Output Interface Circuits

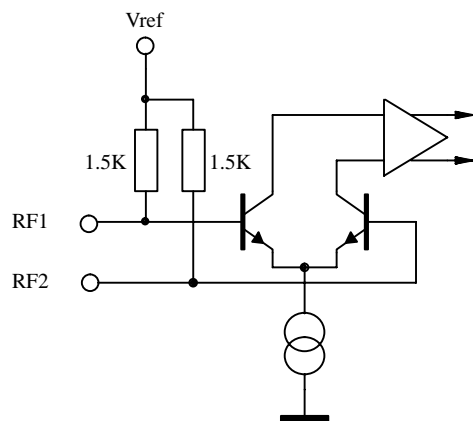


Figure 9. RF Input

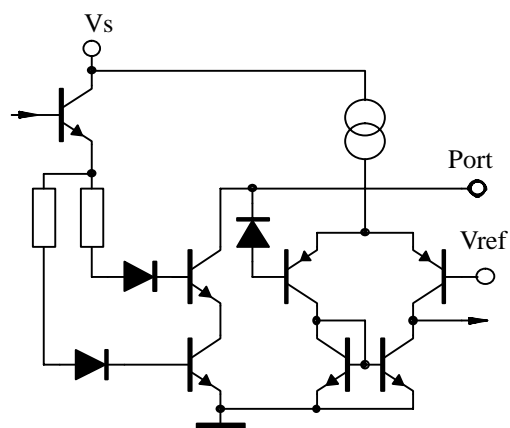


Figure 12. Ports

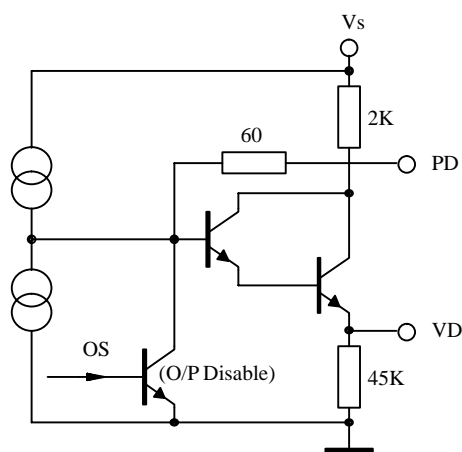


Figure 10. Loop amplifier

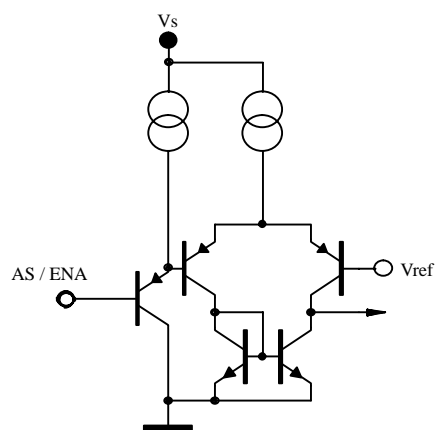


Figure 13. Address select/ Enable input

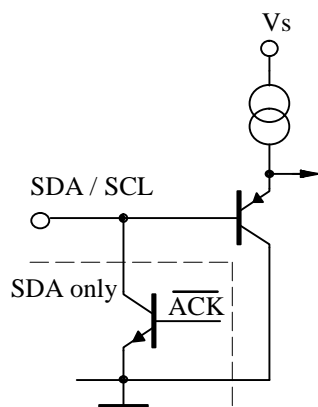


Figure 11. SCL and SDA input

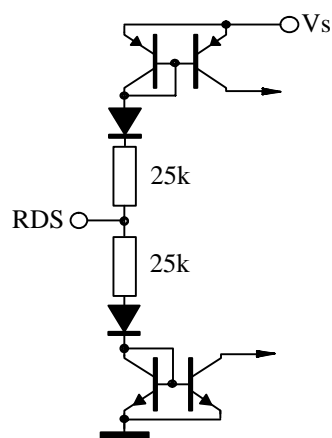


Figure 14. Reference divider select input

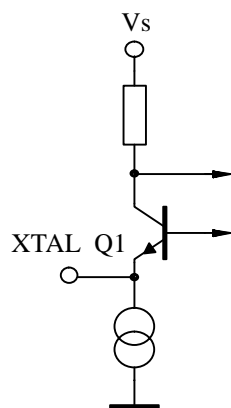


Figure 15. Reference oscillator

Typical Input Impedance

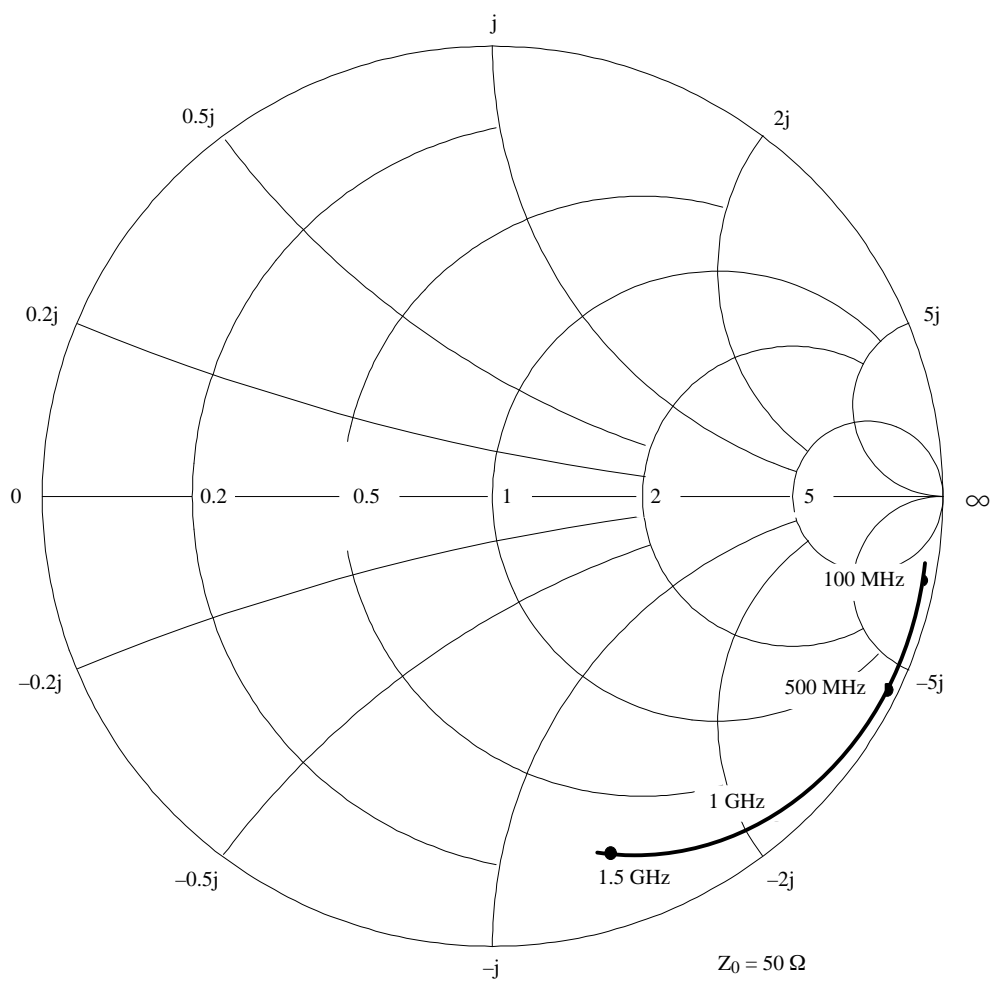


Figure 16.

Application Circuit

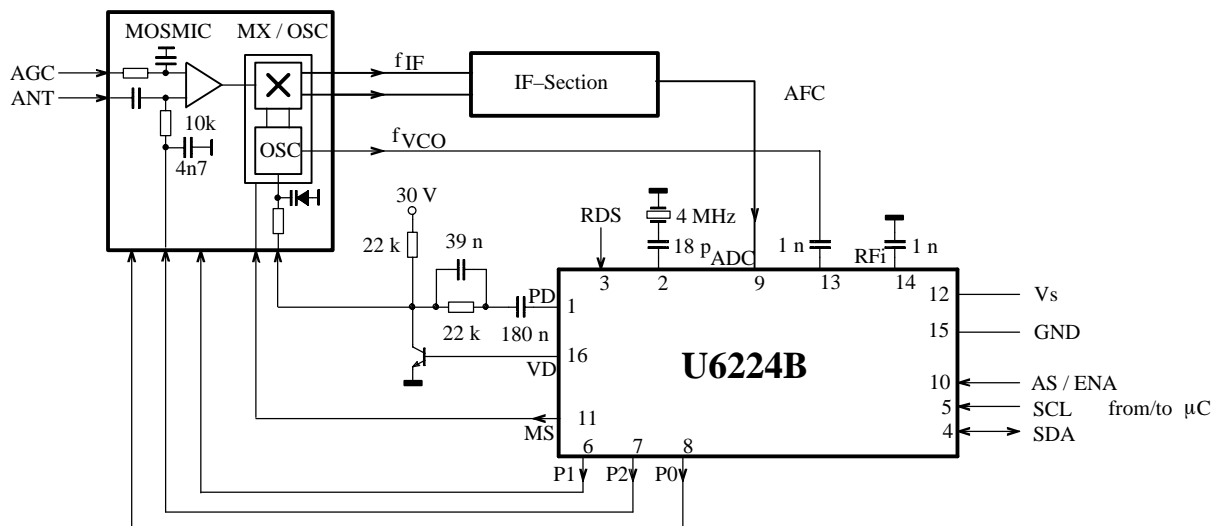
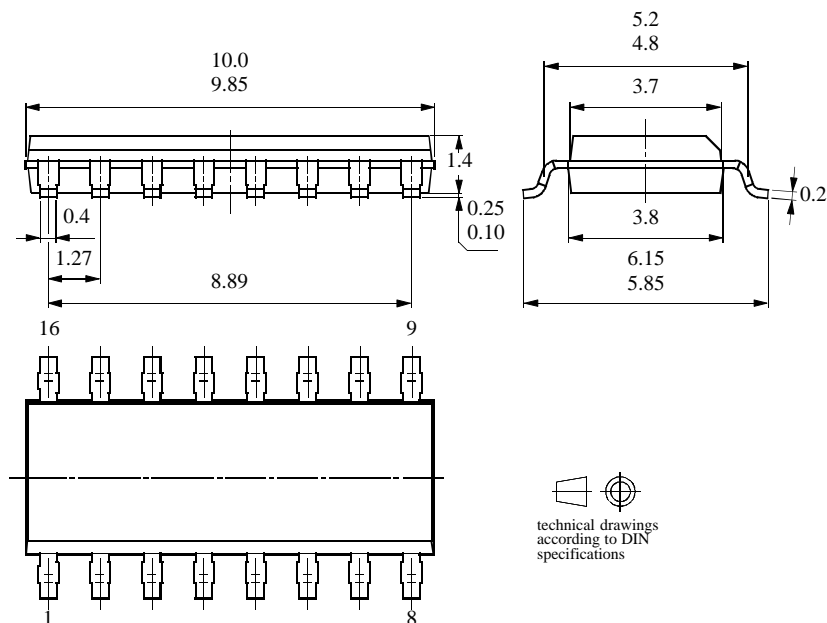


Figure 17. Application circuit

Package Information

Package SO16

Dimensions in mm



technical drawings
according to DIN
specifications

Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify TEMIC Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Data sheets can also be retrieved from the Internet: <http://www.temic-semi.com>

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